

# 2MBI300XBE120-50

IGBT Modules

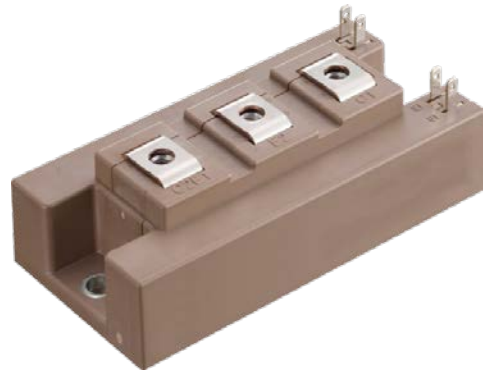
**Power Module (X series)**  
**1200V / 300A / 2-in-1 package**

■ **Features**

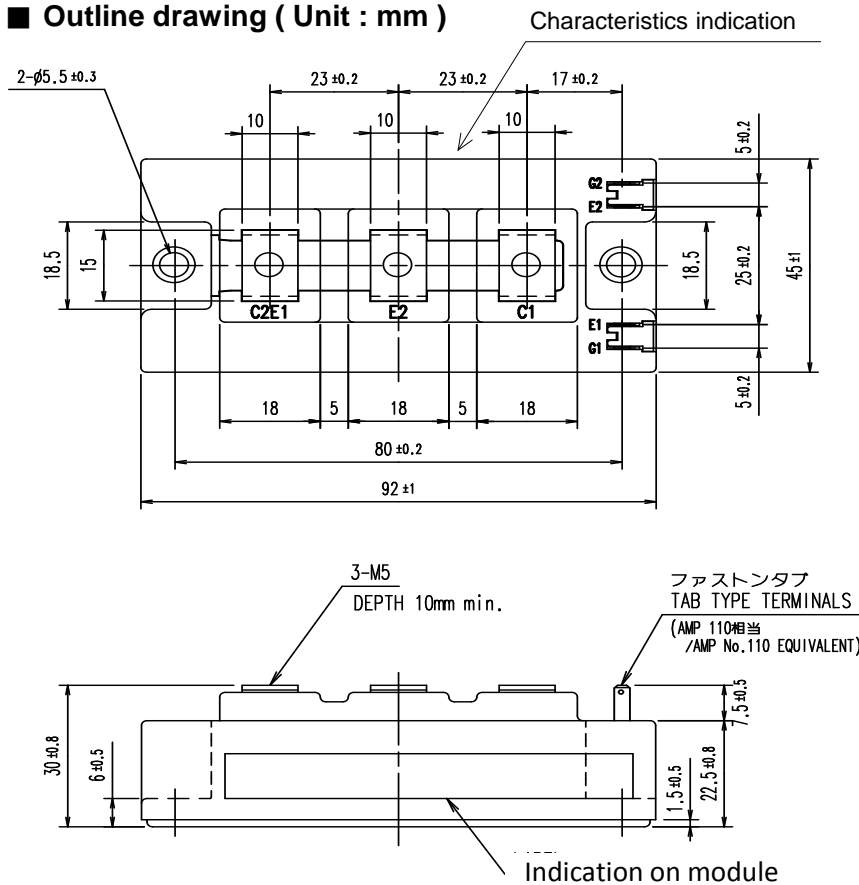
- Low  $V_{CE(sat)}$
- High speed switching
- Low Inductance Module structure

■ **Applications**

- Inverter for Motor Drives, AC and DC Servo Drives
- Uninterruptible Power Supply Systems,
- Industrial machines, such as Welding machines

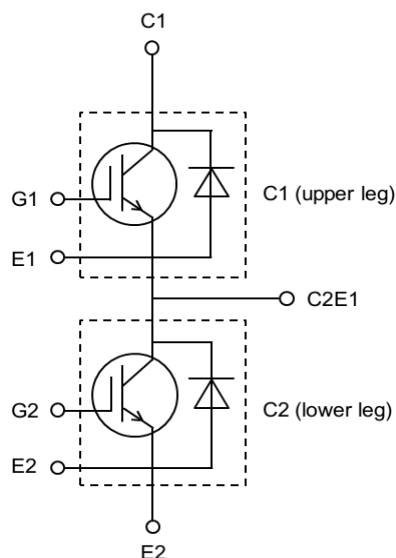


■ **Outline drawing ( Unit : mm )**



Weight: 240 g(typ.)

■ **Equivalent Circuit**



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**■ Absolute Maximum Ratings (at  $T_C=25^\circ\text{C}$  unless otherwise specified)**

Items		Symbols	Conditions		Maximum Ratings	Units	
Inverter	Collector-Emitter voltage, gate-emitter short-circuited	$V_{CES}$			1200	V	
	Gate-Emitter voltage, collector-emitter short-circuited	$V_{GES}$			$\pm 20$	V	
	Collector current	$I_C$	Continuous	$T_C=100^\circ\text{C}$	300	A	
	Repetitive peak collector current	$I_{CRM}$	1ms		600		
	Forward current	$I_F$			300		
	Repetitive peak forward current	$I_{FRM}$	1ms		600		
	Total power dissipation		$P_{tot}$	1 device		1875	W
	Virtual junction temperature		$T_{vj}$			175	$^\circ\text{C}$
	Operating virtual junction temperature		$T_{vjop}$			175	
Case temperature		$T_C$			125		
Storage temperature		$T_{stg}$			-40 ~ 125		
Isolation voltage	between terminal and copper base (*1)	$V_{isol}$	AC: 1min.		4000	Vrms	
Mounting torque of screws to heat sink(*2)		$M_s$	M5		3.5	N m	
Mounting torque of screws to terminals(*2)		$M_t$	M5		3.5		

(\*1) All terminals should be connected together during the test.

 (\*2) Recommendable Value:           Heat sink               2.5 ~ 3.5 N·m   (M5)  
           Recommendable Value:       Terminals           2.5 ~ 3.5 N·m   (M5)

# 2MBI300XBE120-50

■ Electrical characteristics (at  $T_{vj}= 25^{\circ}\text{C}$  unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units			
			min.	typ.	max.				
Collector-Emitter cut-off current, Gate-Emitter short-circuited	$I_{CES}$	$V_{GE} = 0V$ $V_{CE} = 1200V$	-	-	100	$\mu\text{A}$			
Gate leakage current, Collector-Emitter short-circuited	$I_{GES}$	$V_{CE}=0V, V_{GE}=\pm 20V$	-	-	200	nA			
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20V$ $I_C = 300\text{mA}$	6.0	6.5	7.0	V			
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15V$ $I_C = 300A$	$T_{vj}=25^{\circ}\text{C}$	-	1.80	2.25	V		
	$V_{CE(sat)}$ (chip)		$T_{vj}=25^{\circ}\text{C}$	-	1.50	1.95			
			$T_{vj}=125^{\circ}\text{C}$	-	1.90	-			
			$T_{vj}=150^{\circ}\text{C}$	-	1.95	-			
Internal gate resistance	$r_g$	-	$T_{vj}=25^{\circ}\text{C}$	-	1.88	-	$\Omega$		
			Capacitance	$V_{CE}=10V, V_{GE}=0V, f=1\text{MHz}$	$C_{ies}$	-	32	-	nF
					$C_{oes}$	-	1.1	-	
					$C_{res}$	-	0.29	-	
Gate charge	$Q_G$	$V_{CC} = 600V, I_C = 300A$ $V_{GE} = -15 \rightarrow +15V$	-	2.1	-	$\mu\text{C}$			
Forward on voltage	$V_F$ (terminal)	$V_{GE} = 0V$ $I_F = 300A$	$T_{vj}=25^{\circ}\text{C}$	-	1.90	2.35	V		
	$V_F$ (chip)		$T_{vj}=25^{\circ}\text{C}$	-	1.60	2.05			
			$T_{vj}=125^{\circ}\text{C}$	-	1.65	-			
			$T_{vj}=150^{\circ}\text{C}$	-	1.60	-			
Turn-on delay time(*1)	$t_{d(on)}$	$V_{CC} = 600V$ $I_C, I_F = 300A$ $V_{GE} = +15/ -15V$ $R_G = 1.8 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	0.23	-	$\mu\text{s}$		
			$T_{vj}=125^{\circ}\text{C}$	-	0.25	-			
			$T_{vj}=150^{\circ}\text{C}$	-	0.26	-			
			$T_{vj}=175^{\circ}\text{C}$	-	0.26	-			
Rise time(*1)	$t_r$	$V_{CC} = 600V$ $I_C, I_F = 300A$ $V_{GE} = +15/ -15V$ $R_G = 1.8 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	0.05	-			
			$T_{vj}=125^{\circ}\text{C}$	-	0.06	-			
			$T_{vj}=150^{\circ}\text{C}$	-	0.07	-			
			$T_{vj}=175^{\circ}\text{C}$	-	0.07	-			
Turn-off delay time(*1)	$t_{d(off)}$	$V_{CC} = 600V$ $I_C, I_F = 300A$ $V_{GE} = +15/ -15V$ $R_G = 1.8 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	0.35	-			
			$T_{vj}=125^{\circ}\text{C}$	-	0.38	-			
			$T_{vj}=150^{\circ}\text{C}$	-	0.39	-			
			$T_{vj}=175^{\circ}\text{C}$	-	0.40	-			
Fall time(*1)	$t_f$	$V_{CC} = 600V$ $I_C, I_F = 300A$ $V_{GE} = +15/ -15V$ $R_G = 1.8 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	0.11	-			
			$T_{vj}=125^{\circ}\text{C}$	-	0.18	-			
			$T_{vj}=150^{\circ}\text{C}$	-	0.19	-			
			$T_{vj}=175^{\circ}\text{C}$	-	0.21	-			
Reverse recovery time	$t_{rr}$	$V_{CC} = 600V$ $I_C, I_F = 300A$ $V_{GE} = +15/ -15V$ $R_G = 1.8 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	0.15	-			
			$T_{vj}=125^{\circ}\text{C}$	-	0.42	-			
			$T_{vj}=150^{\circ}\text{C}$	-	0.49	-			
			$T_{vj}=175^{\circ}\text{C}$	-	0.56	-			

(\*1) Turn on time ( $t_{on}$ ) =  $t_{d(on)} + t_r$ , Turn off time ( $t_{off}$ ) =  $t_{d(off)} + t_f$

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■ Electrical characteristics (at  $T_{vj}=25^{\circ}\text{C}$  unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units		
			min.	typ.	max.			
Inverter	Turn-on energy	$V_{CC} = 600\text{V}$ $I_C, I_F = 300\text{A}$ $V_{GE} = +15/-15\text{V}$ $R_G = 1.8\ \Omega$ $L_S = 30\ \text{nH}$	$T_{vj}=25^{\circ}\text{C}$	-	18.4	-	mJ	
			$T_{vj}=125^{\circ}\text{C}$	-	31.7	-		
			$T_{vj}=150^{\circ}\text{C}$	-	35.0	-		
			$T_{vj}=175^{\circ}\text{C}$	-	38.4	-		
	Turn-off energy		$E_{off}$	$T_{vj}=25^{\circ}\text{C}$	-	23.6		-
				$T_{vj}=125^{\circ}\text{C}$	-	28.7		-
				$T_{vj}=150^{\circ}\text{C}$	-	29.9		-
				$T_{vj}=175^{\circ}\text{C}$	-	31.2		-
	Reverse recovery energy		$E_{rr}$	$T_{vj}=25^{\circ}\text{C}$	-	13.4		-
				$T_{vj}=125^{\circ}\text{C}$	-	21.7		-
				$T_{vj}=150^{\circ}\text{C}$	-	23.7		-
				$T_{vj}=175^{\circ}\text{C}$	-	25.8		-

NOTICE:

The external gate resistance ( $R_G$ ) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum  $R_G$  depends on circuit configuration and/or environment. We recommend that the  $R_G$  has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

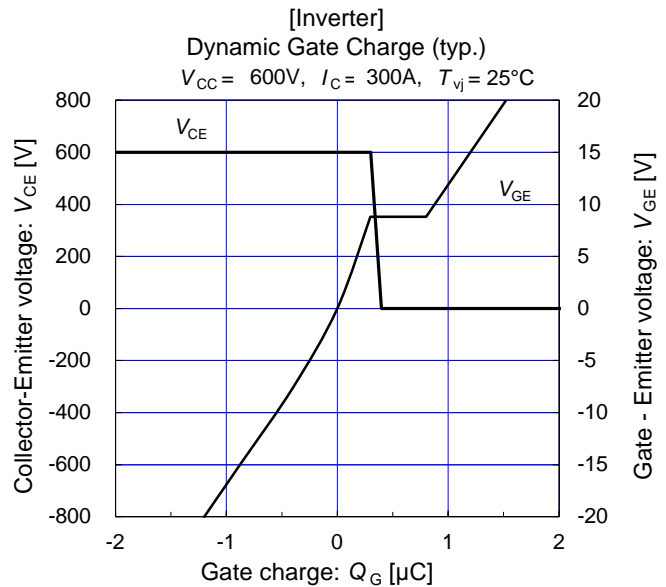
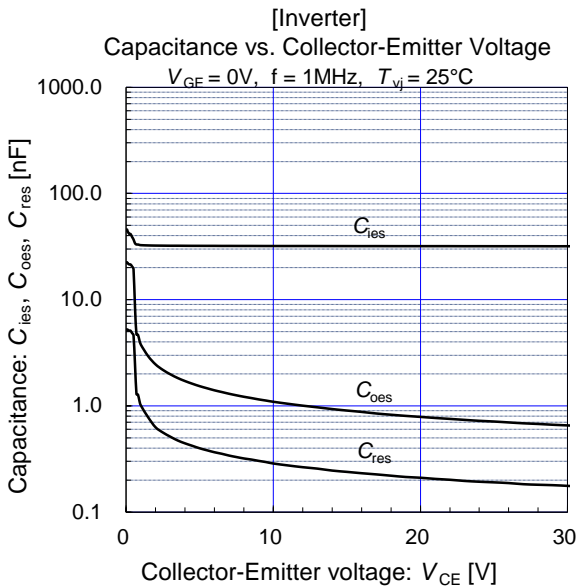
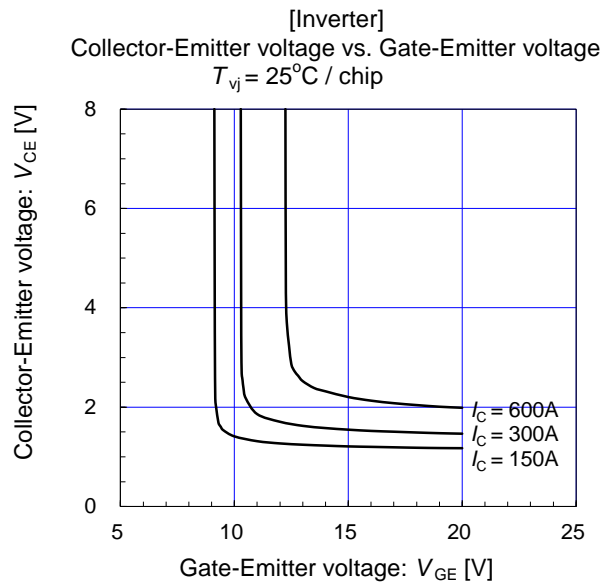
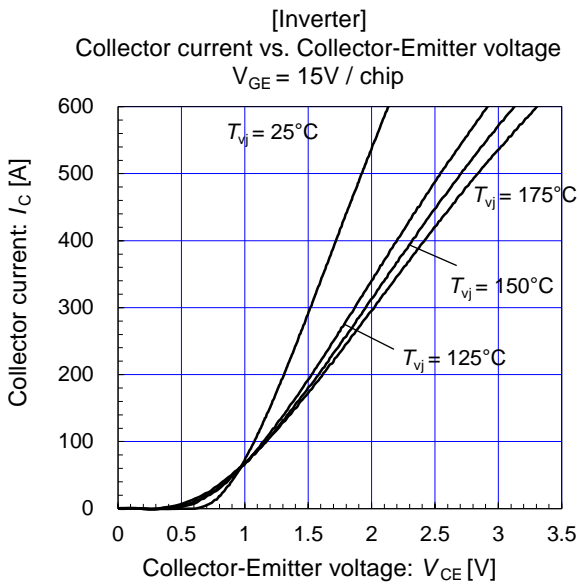
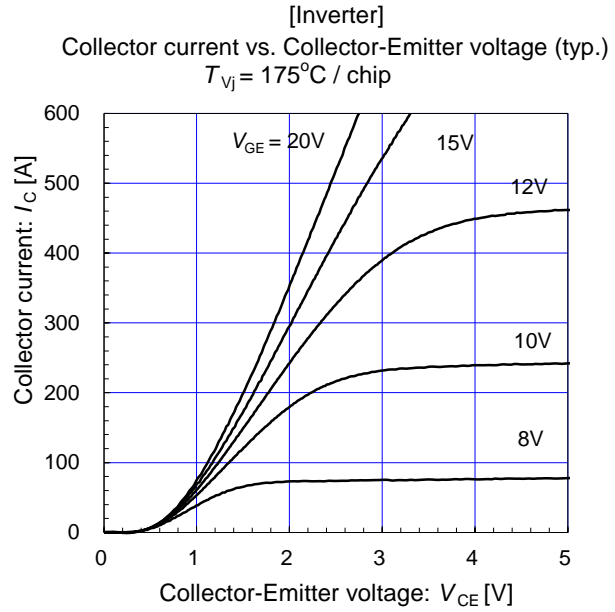
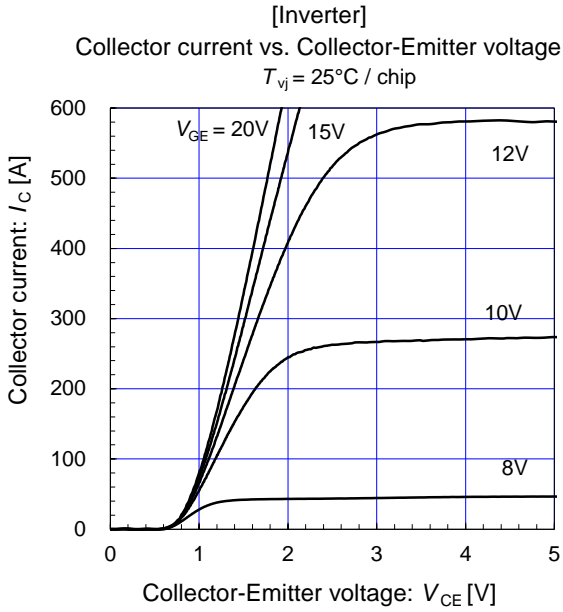
■ Thermal resistance characteristics

	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance junction to case (1device)	$R_{th(j-c)}$	Inverter IGBT	-	-	0.080	$^{\circ}\text{C/W}$
		Inverter FWD	-	-	0.105	
Thermal resistance case to heat sink (1 IGBT + 1FWD) (*1)	$R_{th(c-s)}$	with 1 W/(m·K) thermal grease	-	0.025	-	

(\*1) This is the value which is defined mounting on the additional heat sink with thermal grease.

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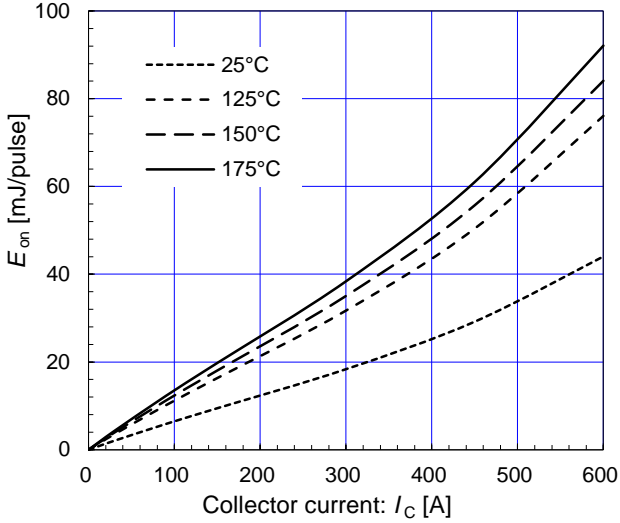
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[Inverter]

$E_{on}$  vs. Collector current (typ.)

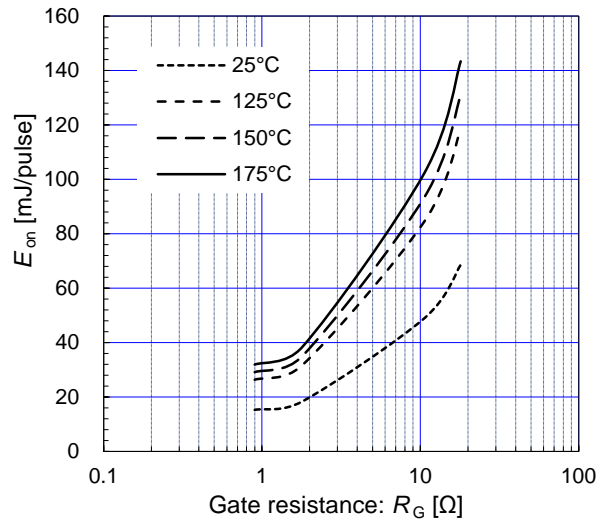
$V_{CC} = 600V, V_{GE} = +15/-15V, R_G = 1.8 \Omega$



[Inverter]

$E_{on}$  vs. Gate resistance (typ.)

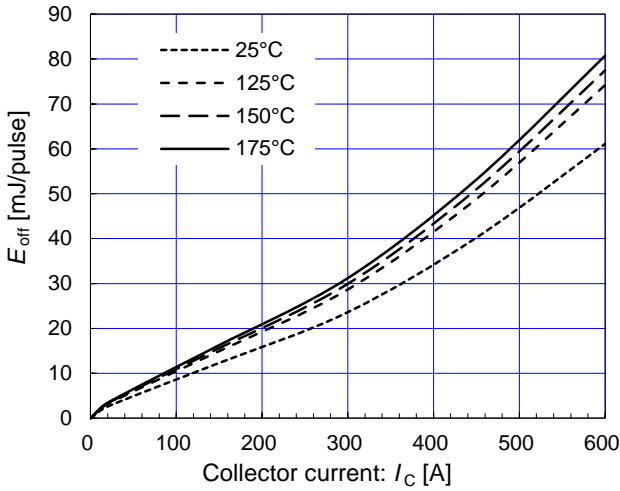
$V_{CC} = 600V, V_{GE} = +15/-15V, I_C = 300A$



[Inverter]

$E_{off}$  vs. Collector current (typ.)

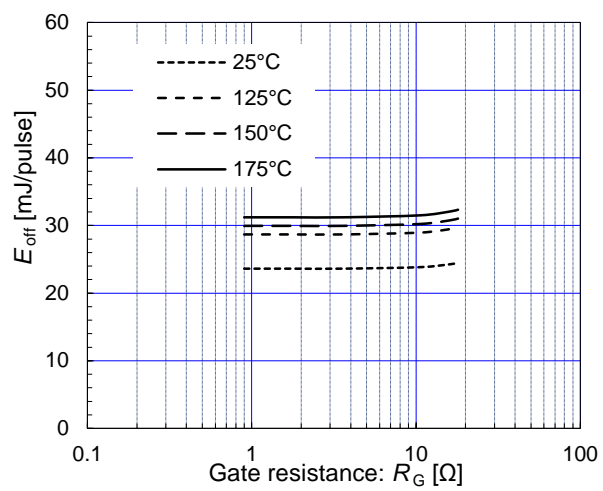
$V_{CC} = 600V, V_{GE} = +15/-15V, R_G = 1.8 \Omega$



[Inverter]

$E_{off}$  vs. Gate resistance (typ.)

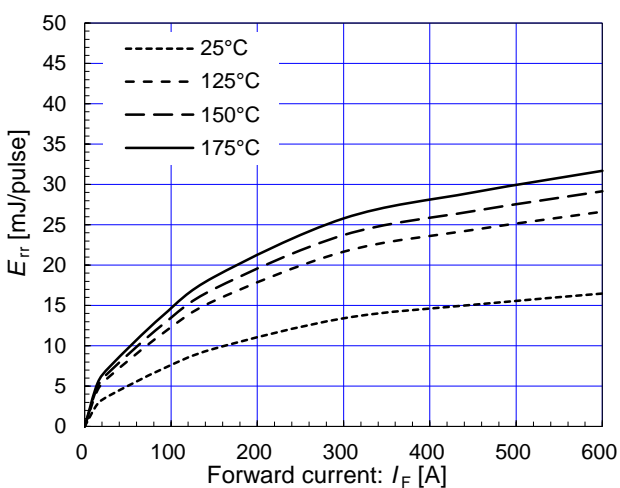
$V_{CC} = 600V, V_{GE} = +15/-15V, I_C = 300A$



[Inverter]

$E_{rr}$  vs. Forward current (typ.)

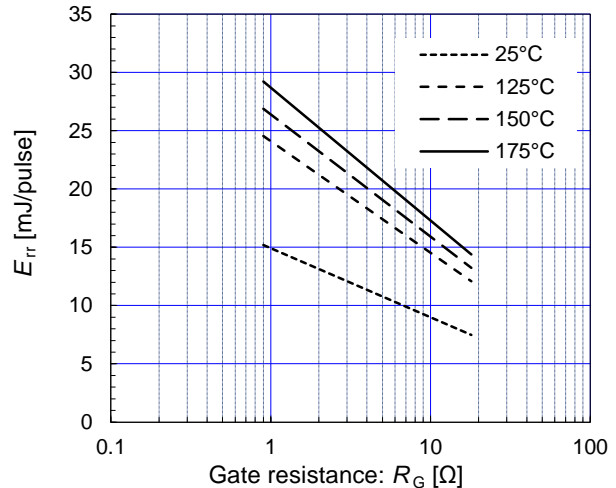
$V_{CC} = 600V, V_{GE} = +15/-15V, R_G = 1.8 \Omega$



[Inverter]

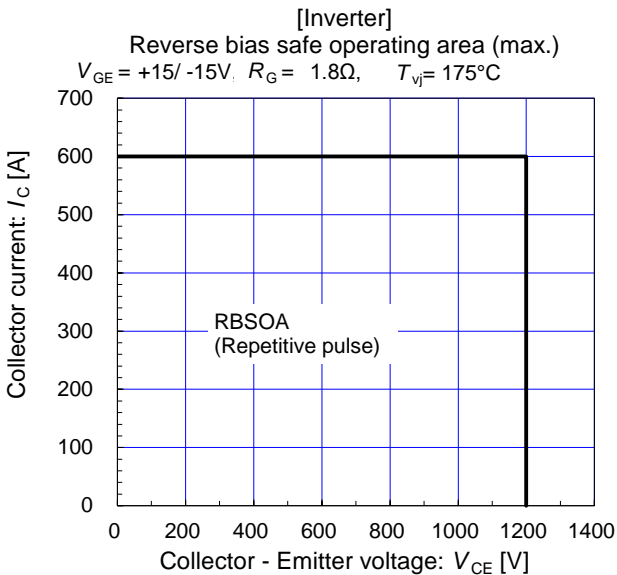
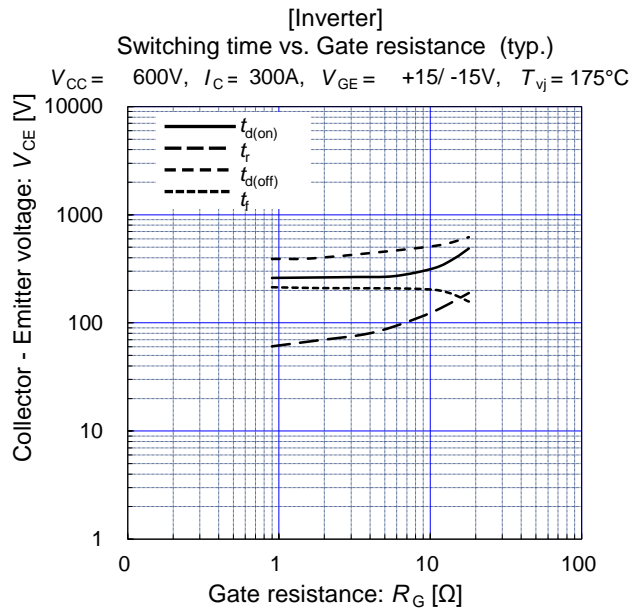
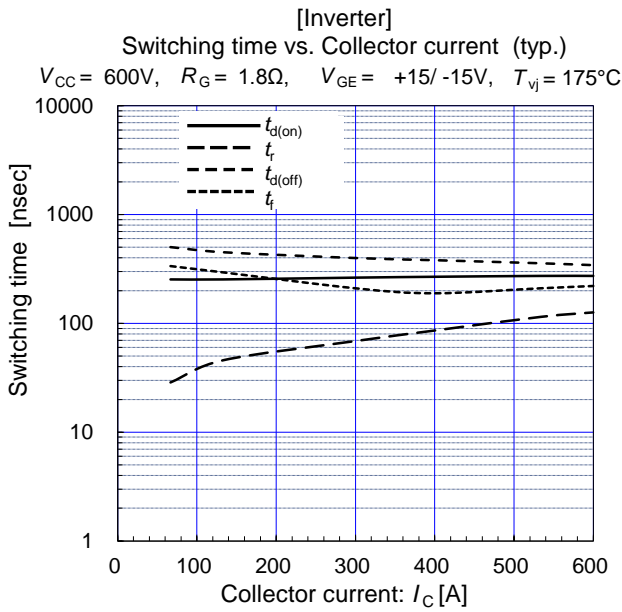
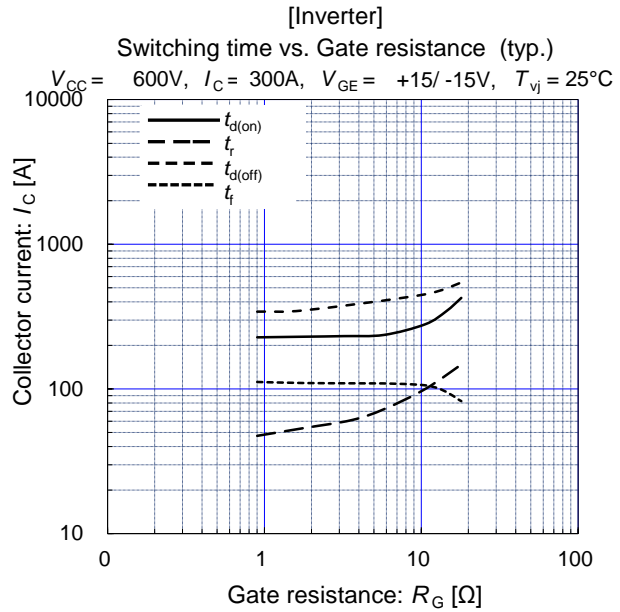
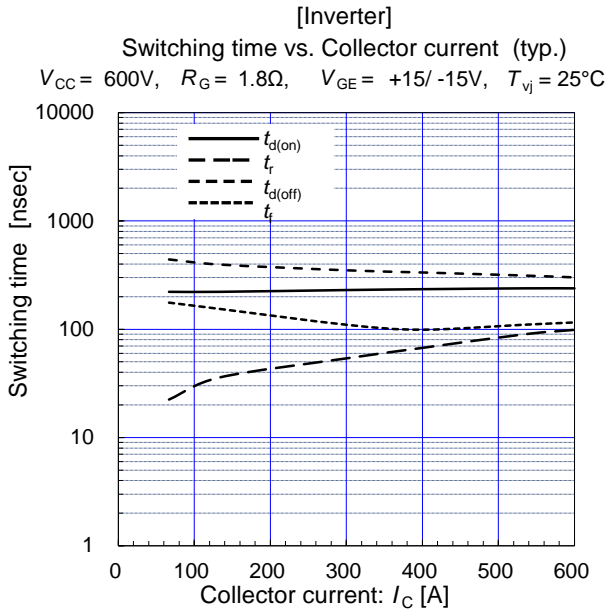
$E_{rr}$  vs. Gate resistance (typ.)

$V_{CC} = 600V, V_{GE} = +15/-15V, I_C = 300A$



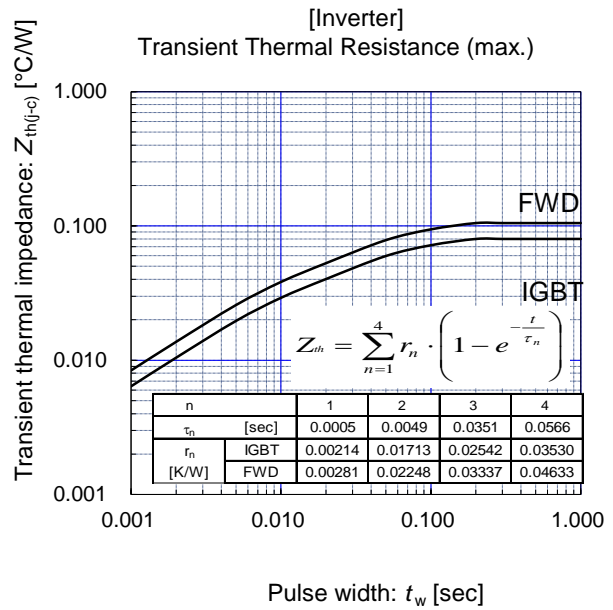
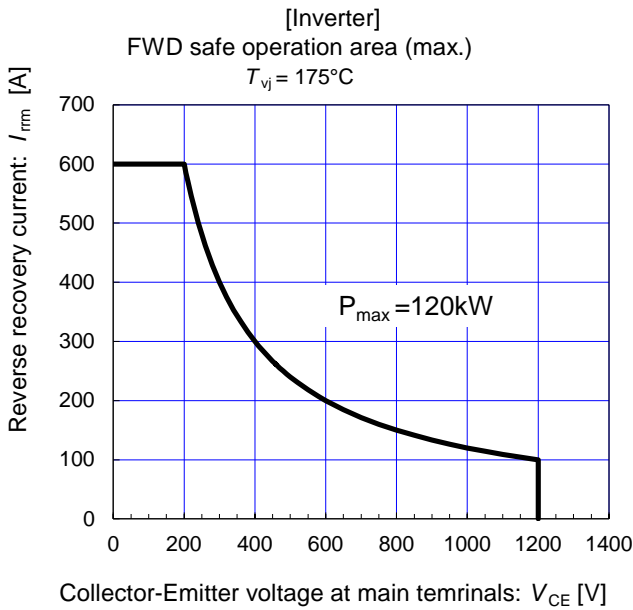
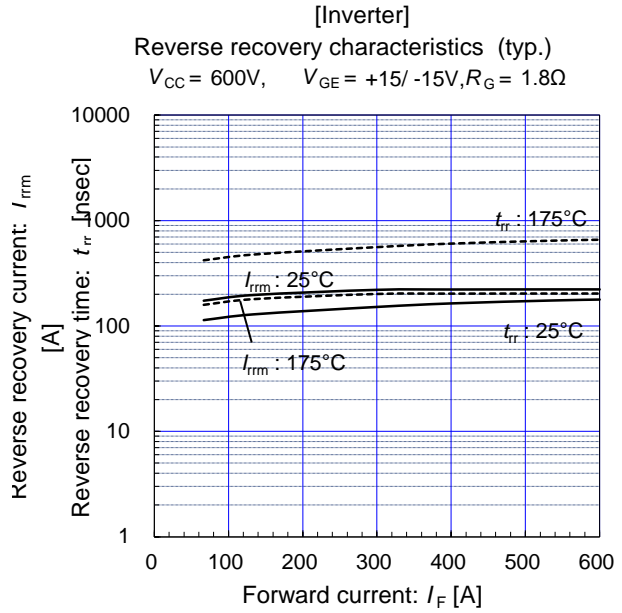
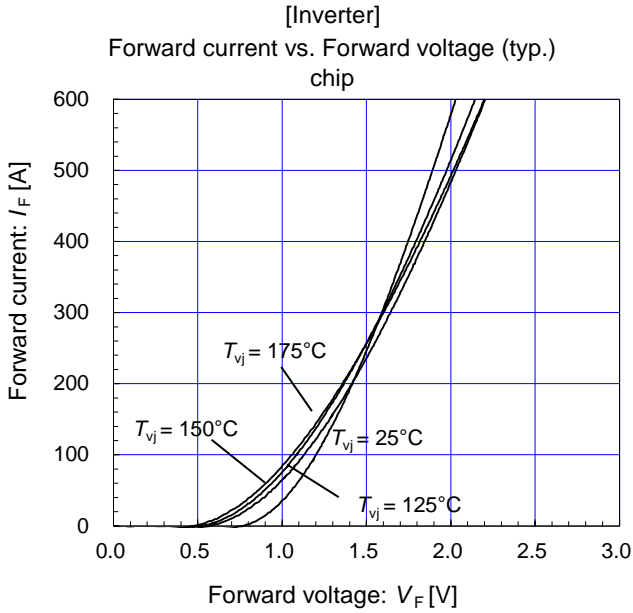
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6 IGBT 损耗模拟软件	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation/">www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation/</a>
7 富士电机技报	<a href="http://www.fujielectric.com.cn/products/semiconductor/journal/">www.fujielectric.com.cn/products/semiconductor/journal/</a>
8 产品咨询	<a href="http://www.fujielectric.com/contact/">www.fujielectric.com/contact/</a>
9 产品更改和停产信息	<a href="http://www.fujielectric.com.cn/products/semiconductor/discontinued/">www.fujielectric.com.cn/products/semiconductor/discontinued/</a>